

## **Features**

- 2.5V-5.5V power supply
- Isolation voltage is 3kV RMS
- The CMTI of common mode
- transient suppression was up to 150KV/uS
- 2.1V undervoltage protection
- Maximum signal transmission is 90Mbps
- Transmission latency is as low as 10ns
- Pulse width distortion was as low as 5ns
- Static power consumption is as low as 300uA
- The dynamic power consumption is 6mA / channel
- Operating temperature support from -40°C to +85°C

## **Application**

- Industrial control signal transmission
- Grid relay protection device
- Isolated power control
- Replace Optocoupler
- Industrial motor control
- Solar inverter

## **Description**

The CBMuD120X series is a high-speed 2-channel digital isolator. Integrated high-performance capacitive isolation technology. The maximum signal transmission rate is up to 90Mbps, with small pulse width distortion. The device can withstand a high isolation voltage and meets the conventional one Test Specifications (UL Standards). No requirements for the external electromagnetic field environment.

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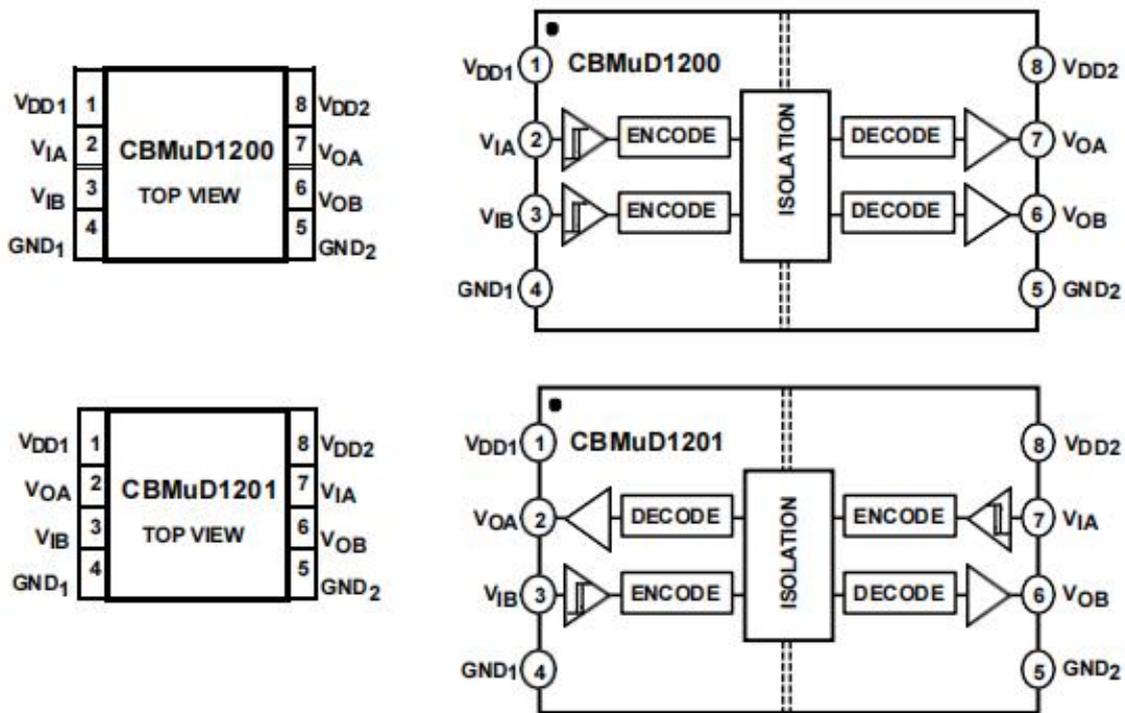
## Revision Log

Version	Revision date	Change content	Reason for Change	Modified by	Reviewed By	Note
V1.0	2024.12.25	Adjust the lower limit of the product's IDD parameters.	Regular update	WW	LYL	
V1.1	2025.5.6	Increase the product's static parameters.	Regular update	WW	LYL	

## Product selection, pin assignment and block diagram

Product model	Function definition	Default output
CBMuD1201L	Two-way	The default output is low
CBMuD1201H	Two-way	The default output is high
CBMuD1200L	One-way	The default output is low
CBMuD1200H	One-way	The default output is high

Product selection



pin assignment and block diagram

**Truth Table**

CBMuD1200H, CBMuD1201H Truth Table

VIA Input	VIB Input	VDD1 Status	VDD2 Status	VOA Output	VOB Output
H	H	Power on	Power on	H	H
L	L	Power on	Power on	L	L
H	L	Power on	Power on	H	L
L	H	Power on	Power on	L	H
X	X	Not powered on	Power on	H	H
X	X	Power on	Not powered on	X	X

CBMuD1200L, CBMuD1201L Truth Table

VIA Input	VIB Input	VDD1 Status	VDD2 Status	VOA Output	VOB Output
H	H	Power on	Power on	H	H
L	L	Power on	Power on	L	L
H	L	Power on	Power on	H	L
L	H	Power on	Power on	L	H
X	X	Not powered on	Power on	L	L
X	X	Power on	Not powered on	X	X

## Absolute Maximum Ratings <sup>(1)</sup>

### Absolute electrical parameters

Symbol	Parameters	Min	Max	Units
V <sub>CC</sub>	Supply voltage	-0.3	6	V
V <sub>IO</sub>	I/O service voltage	GND-0.3	VCC+0.5	
I <sub>O</sub>	I/O port maximum output current	-50	+50	mA
T <sub>J</sub>	Junction temperature		150	°C
T <sub>S</sub>	Storage temperature	-50	150	°C
T <sub>J</sub>	Junction temperature	-	150	°C

## ESD

### Electrostatic protection parameters

Symbol	Parameters		Units
VESD-HBM	Human Body Model, per ANSI/ESDA/JEDEC JS-001	±3000	V
VESD-CDM	Charged Device Model, per JEDEC specification JESD22-C101	±500	V

## Recommended Operating Condition

At T<sub>A</sub> = -40°C to 85°C, V<sub>S</sub> = 2.5V to 5.5V (unless otherwise specified)

Symbol	Parameter	Test Condition	Min	Typ	Max	Units
VDD	Supply Voltage	Operating	2.5	-	5.5	
V <sub>IH</sub>	Logic input is a high level		0.7xVDD			V
V <sub>IL</sub>	Logical low-level input				0.3xVDD	V
	Rated electrolyte isolation voltage	For 1 minute	3000			V RMS
	Minimum external creepage distance	Measure input to output, the shortest distance along the shell	3.9			mm
	Minimum gap between PCB layers	The shortest distance of each layer of PCB power domain	3.9			mm

According to the following standards, insulation certification has been passed and safety has been confirmed.

Item	Electrical safety standard	Description
1	UL 1577	Standard for safety: Optical isolators
2	IEC 60601-1	Medical electrical equipment-Part 1: General requirements for basic safety and essential performance
3	IEC 61010-1	Safety requirements for electrical equipment for measurement, control and laboratory use-Part1: General requirements
4	IEC 60950-1	Information technology equipment-Safety -Part 1: General requirements
5	GB 4943.1-2011	Information technology equipment-Safety -Part 1: General Requirements
6	DIN VDE V 0884-11(VDE V 0884-11):2017-01	Magnetic and capacitive coupler for basic and reinforced isolation

## Electrical Characteristics

Performance parameters under 2.5V power supply (At  $T_A = -40^{\circ}\text{C}$  to  $85^{\circ}\text{C}$ ,  $V_{DD1}=V_{DD2}=2.5\text{V}$ )

Parameter	Symbol	Min	Max		Test Condition	Units
Data rate	DR	--	90	--		Mbps
High to low transmission latency	$t_{PHL}$	--	10	13	50% input to 50% output	ns
Low to high transmission latency	$t_{PLH}$	--	10	13	50% input to 50% output	ns
Minimum pulse width	PW	10	--	--		ns
Channel matching	$t_M$	--	--	3		ns
Pulse distortion	PWD	--	--	6		ns
Output up time	$t_r$	1.5	2	3	Output rise time, 10%~90% 10pF load	ns
Output drop time	$t_f$	1.5	2	3	Lower up time, 90%~10% 10pF load	ns
Power static current	$I_{DDI(Q)}$	--	280	--	Enter the suspension	$\mu\text{A}/\text{channel}$
Dynamic power current	$I_{DDI(D)}$	--	5.4	6.4	The input signal is 2Mbps, $C_L=10\text{pF}$	$\text{mA}/\text{channel}$
Dynamic power current	$I_{DDI(D)}$	--	8	9.2	The input signal is 20Mbps, $C_L=10\text{pF}$	$\text{mA}/\text{channel}$
Dynamic power current	$I_{DDI(D)}$	--	12.7	15.2	The input signal is 60Mbps, $C_L=10\text{pF}$	$\text{mA}/\text{channel}$
Input Currents	$I_{IA}, I_{IB}$	-10	+0.01	+10	$0\text{V} \leq V_{IA}, V_{IB} \leq (V_{DD1} \text{ or } V_{DD2})$	$\mu\text{A}$
Logic High Input Threshold	$V_{IH}$	0.7 ( $V_{DD1}$ or $V_{DD2}$ )	--	--	--	V
Logic Low Input Threshold	$V_{IL}$	--	--	0.3 ( $V_{DD1}$ or $V_{DD2}$ )	--	V
Logic High Output Voltages	$V_{OAH}, V_{OBH}$	$V_{DD1}$ or	2.5	--	$I_{Ox} = -20\ \mu\text{A}, V_{Ix} = V_{IxH}$	V

		$V_{DD2}$ - 0.1				
		( $V_{DD1}$ or $V_{DD2}$ ) - 0.5	2.3	--	$I_{Ox} = -4 \text{ mA}, V_{Ix} = V_{IxH}$	V
Logic Low Output Voltages	$V_{OAL}, V_{OBL}$	--	0	0.1	$I_{Ox} = 20 \text{ }\mu\text{A}, V_{Ix} = V_{IxL}$	V
		--	0.04	0.1	$I_{Ox} = 400 \text{ }\mu\text{A}, V_{Ix} = V_{IxL}$	V
		--	0.2	0.4	$I_{Ox} = 4 \text{ mA}, V_{Ix} = V_{IxL}$	V

Performance parameters under 3.3V power supply (At  $T_A = -40^\circ\text{C}$  to  $85^\circ\text{C}$ ,  $V_{DD1}=V_{DD2}=3.3\text{V}$ )

Parameter	Symbol	Min	Max		Test Condition	Units
Data rate	DR	--	90	--		Mbps
High to low transmission latency	$t_{PHL}$	--	7	12	50% input to 50% output	ns
Low to high transmission latency	$t_{PLH}$	--	7	12	50% input to 50% output	ns
Minimum pulse width	PW	10	--	--		ns
Channel matching	$t_M$	--	--	3		ns
Pulse distortion	PWD	--	--	6		ns
Output up time	$t_r$	1.5	2	3	Output rise time, 10%~90% 10pF load	ns
Output drop time	$t_f$	1.5	2	3	Lower up time, 90%~10% 10pF load	ns
Power static current	$I_{DDI(Q)}$	--	290	--	Enter the suspension	$\mu\text{A}/\text{channel}$
Dynamic power current	$I_{DDI(D)}$	--	6.1	7.2	The input signal is 2Mbps, $C_L=10\text{pF}$	$\text{mA}/\text{channel}$
Dynamic power current	$I_{DDI(D)}$	--	9.3	11	The input signal is 20Mbps, $C_L=10\text{pF}$	$\text{mA}/\text{channel}$
Dynamic power current	$I_{DDI(D)}$	--	16.2	19	The input signal is 60Mbps, $C_L=10\text{pF}$	$\text{mA}/\text{channel}$
Input Currents	$I_{IA}, I_{IB}$	-10	+0.01	+10	$0 \text{ V} \leq V_{IA}, V_{IB} \leq (V_{DD1} \text{ or } V_{DD2})$	$\mu\text{A}$
Logic High Input Threshold	$V_{IH}$	0.7 ( $V_{DD1}$ or 0.5)	--	--	--	V

		$V_{DD2}$				
Logic Low Input Threshold	$V_{IL}$	--	--	0.3 ( $V_{DD1}$ or $V_{DD2}$ )	--	V
Logic High Output Voltages	$V_{OAH}, V_{OBH}$	$V_{DD1}$ or $V_{DD2}$ - 0.1	3.3	--	$I_{Ox} = -20 \mu A, V_{Ix} = V_{IxH}$	V
		( $V_{DD1}$ or $V_{DD2}$ ) - 0.5	3.1	--	$I_{Ox} = -4 \text{ mA}, V_{Ix} = V_{IxH}$	V
Logic Low Output Voltages	$V_{OAL}, V_{OBL}$	--	0	0.1	$I_{Ox} = 20 \mu A, V_{Ix} = V_{IxL}$	V
		--	0.04	0.1	$I_{Ox} = 400 \mu A, V_{Ix} = V_{IxL}$	V
		--	0.2	0.4	$I_{Ox} = 4 \text{ mA}, V_{Ix} = V_{IxL}$	V

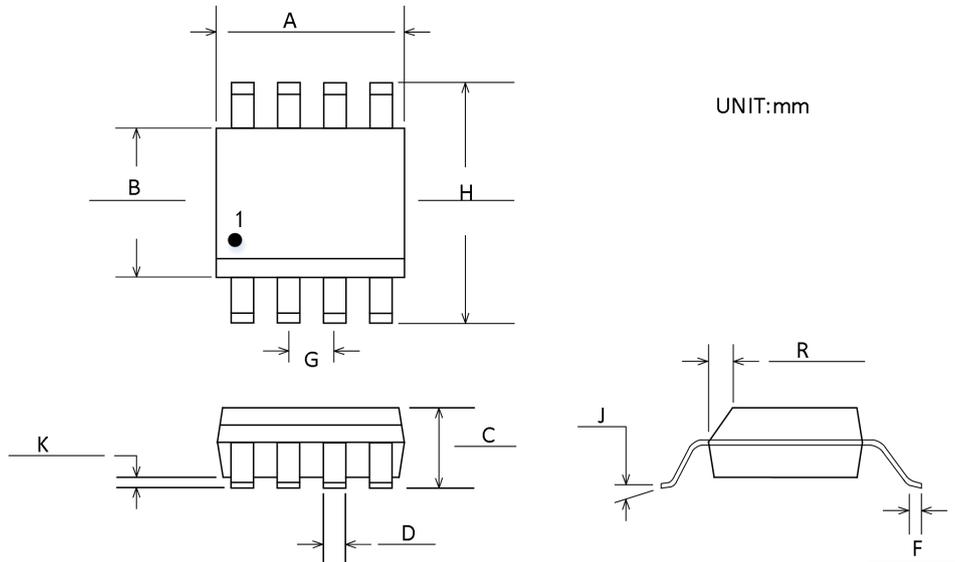
Performance parameters under 5V power supply (At  $T_A = -40^\circ\text{C}$  to  $85^\circ\text{C}$ ,  $V_{DD1}=V_{DD2}=5\text{V}$ )

Parameter	Symbol	Min	Max		Test Condition	Units
Data rate	DR	--	90	--		Mbps
High to low transmission latency	$t_{PHL}$	--	5	8	50% input to 50% output	ns
Low to high transmission latency	$t_{PLH}$	--	5	8	50% input to 50% output	ns
Minimum pulse width	PW	10	--	--		ns
Channel matching	$t_M$	--	--	3		ns
Pulse distortion	PWD	--	--	6		ns
Output up time	$t_r$	1.5	2	3	Output rise time, 10%~90% 10pF load	ns
Output drop time	$t_f$	1.5	2	3	Lower up time, 90%~10% 10pF load	ns
Power static current	$I_{DDI(Q)}$	--	300	--	Enter the suspension	$\mu A/\text{channel}$
Dynamic power current	$I_{DDI(D)}$	--	9.4	11.4	The input signal is 2Mbps, $C_L=10\text{pF}$	$\text{mA}/\text{channel}$
Dynamic power	$I_{DDI(D)}$	--	12.1	14.5	The input signal is 20Mbps, $C_L=10\text{pF}$	$\text{mA}/\text{channel}$

current						nnel
Dynamic power current	$I_{DD(D)}$	--	22	26	The input signal is 60Mbps, $C_L=10pF$	mA/channel
Input Currents	$I_{IA}, I_{IB}$	-10	+0.01	+10	$0V \leq V_{IA}, V_{IB} \leq (V_{DD1} \text{ or } V_{DD2})$	$\mu A$
Logic High Input Threshold	$V_{IH}$	0.7 ( $V_{DD1}$ or $V_{DD2}$ )	--	--	--	V
Logic Low Input Threshold	$V_{IL}$	--	--	0.3 ( $V_{DD1}$ or $V_{DD2}$ )	--	V
Logic High Output Voltages	$V_{OAH}, V_{OBH}$	$V_{DD1}$ or $V_{DD2}$ - 0.1	5	--	$I_{Ox} = -20 \mu A, V_{Ix} = V_{IxH}$	V
		( $V_{DD1}$ or $V_{DD2}$ ) - 0.5	4.8	--	$I_{Ox} = -4 mA, V_{Ix} = V_{IxH}$	V
Logic Low Output Voltages	$V_{OAL}, V_{OBL}$	--	0	0.1	$I_{Ox} = 20 \mu A, V_{Ix} = V_{IxL}$	V
		--	0.04	0.1	$I_{Ox} = 400 \mu A, V_{Ix} = V_{IxL}$	V
		--	0.2	0.4	$I_{Ox} = 4 mA, V_{Ix} = V_{IxL}$	V

## Package Outline Dimensions

### SOP-8



Symbol	Dimensions In Millimeters	
	Min	Max
A	4.80	5.00
B	3.80	4.00
C	1.35	1.75
D	0.31	0.51
F	0.40	1.27
G	1.27BSC	
H	5.80	6.20
J	0°	8°
K	0.10	0.25
R	0.25	0.50

SOP8 Package outline dimension

## Package/Ordering Information

Product Type	Operating Temperature	Package	Package Marking	Number of Packages
CBMuD1200LAS8	-40°C~85°C	SOP-8	1200LA	编带和卷盘,每卷 2500
CBMuD1200LAS8-RL	-40°C~85°C	SOP-8	1200LA	编带和卷盘,每卷 3000
CBMuD1200LAS8-RL	-40°C~85°C	SOP-8	1200LA	编带和卷盘,每卷 4000
CBMuD1200HAS8	-40°C~85°C	SOP-8	1200HA	编带和卷盘,每卷 2500
CBMuD1200HAS8-RL	-40°C~85°C	SOP-8	1200HA	编带和卷盘,每卷 3000
CBMuD1200HAS8-RL	-40°C~85°C	SOP-8	1200HA	编带和卷盘,每卷 4000
CBMuD1201LAS8	-40°C~85°C	SOP-8	1201LA	编带和卷盘,每卷 2500
CBMuD1201LAS8-RL	-40°C~85°C	SOP-8	1201LA	编带和卷盘,每卷 3000
CBMuD1201LAS8-RL	-40°C~85°C	SOP-8	1201LA	编带和卷盘,每卷 4000
CBMuD1201HAS8	-40°C~85°C	SOP-8	1201HA	编带和卷盘,每卷 2500
CBMuD1201HAS8-RL	-40°C~85°C	SOP-8	1201HA	编带和卷盘,每卷 3000
CBMuD1201HAS8-RL	-40°C~85°C	SOP-8	1201HA	编带和卷盘,每卷 4000